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OFFICIAL

ONS00181
PATENT

IN THE UNITED STATES ~~PATENT~~ AND TRADEMARK OFFICE

In re application of: : Date: November 19, 2003

Peyman Hadizad et al. :

Serial No.: 09/802,726 : Group Art Unit: 2813

Filed: March 12, 2001 : Examiner: Laura M.
Schillinger

For: SEMICONDUCTOR COMPONENT AND METHOD OF MANUFACTURING

I HEREBY CERTIFY THAT THIS CORRESPONDENCE IS BEING FACSIMILE
TRANSMITTED TO THE PATENT AND TRADEMARK OFFICE, ATTENTION
EXAMINER Laura M. Schillinger, AT THE FAX NUMBER (703) 872-
9318, ON: NOV. 19, 2003 No. of Pages: 34

Date of Facsimile Transmission

LYDIA McNamee

Name of Person Signing Certificate

Lydia McNamee

SIGNATURE

11/19/03
DATE

PETITION UNDER 37 CFR 1.97(d), CERTIFICATION UNDER 37 CFR
1.97(e), AND DISCLOSURE STATEMENT UNDER 37 CFR 1.56

HONORABLE ASSISTANT COMMISSIONER FOR PATENTS,
Alexandria, VA 22313-1450

Sir:

Applicants herewith petition the Commissioner of
Patents to consider this information disclosure statement.

Please charge Deposit Account No. 501086 in the amount
of \$180.00 in accordance with 37 CFR 1.17(p). Any
deficiency or overpayment should be charged or credited to
the above stated Deposit Account.

Applicants respectfully request that the Examiner
consider the art listed below in the examination of the
subject application and that it be made of record therein.

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Applicants have enclosed copies of the below listed documents. No warranty is made or implied that an exhaustive search has been conducted or that no other or no more relevant art exists.

I hereby certify that to my knowledge, after reasonable inquiry, no item contained in this information disclosure statement was known to any individual designated in 37 CFR 1.56(c) more than three months prior to the filing of this information disclosure statement.

1. U.S. Patent No. 6,608,350 B2 issued to Kinzer et al. on August 19, 2003, which discloses a vertical conduction superjunction semiconductor device.
2. U.S. Patent No. 6,509,240 B2 issued to Ren et al. on January 21, 2003, which discloses a method of forming a portion of a superjunction semiconductor device.
3. U.S. Patent No. 6,410,958 B1 issued to Usui et al. on June 25, 2002, which discloses a vertical superjunction semiconductor device.

Respectfully submitted,

Peyman Hadizad et al.



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